



Volume I

Essential Topics in Optoelectronics

Annie Kent



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Volume I

Edited by **Annie Kent**

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Edited by Annie Kent

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Essential Topics in Optoelectronics

Volume I

Preface

Optoelectronics is a field of science which studies about concepts and applications of electronic devices that produce light and are used in the detection of light and for controlling light. It wouldn't be wrong to say that this subject is a sub-field of photonic sciences. In this context, it is pertinent to state that light includes radiations like gamma rays, X-rays, UV rays, infrared radiations, and visible lights that are VIBGYOR. Devices which are optoelectronic in nature are basically electrical to optical transducers and vice-versa. Also included in Optoelectronics are the instruments which use such devices in their operational procedures. Also referred to as electro-optics, this field of study is based on quantum mechanical study of light and its effects on electronic materials such as semiconductors. Important applications of optoelectronics include Optocoupler and Optical fibre communications among numerous others.

A good base in physics is crucial for developing an understanding of Optoelectronics. This book elucidates the fundamentals of light modulation, essential concepts of optics and solid state physics. Non communication applications of Optoelectronics have also been discussed. From basic to advanced concepts, most aspects of Optoelectronics have been covered in this book.

Instead of organizing the book into a pre-formatted table of contents with chapters, sections and then asking the authors to submit their respective chapters based on this frame, the authors were encouraged by the publisher to submit their chapters based on their area of expertise. I was then commissioned to examine the reading material and put it together as a book. I'd like to thank all the renowned scientists, who graciously agreed to share their researches with us. Lastly, this project wouldn't have been possible without the editorial team at the publishing house, who provided us with technical assistance at each and every step.

Editor

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Nonlinear Scattering by Anisotropic Dielectric Periodic Structures

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The combinatorial frequency generation by the periodic stacks of binary layers of anisotropic nonlinear dielectrics is examined. The products of nonlinear scattering are characterised in terms of the three-wave mixing processes. It is shown that the intensity of the scattered waves of combinatorial frequencies is strongly influenced by the constitutive and geometrical parameters of the anisotropic layers, and the frequency ratio and angles of incidence of pump waves. The enhanced efficiency of the frequency conversion at Wolf-Bragg resonances has been demonstrated for the lossless and lossy-layered structures.

1. Introduction

A new generation of artificial electromagnetic materials has opened up new opportunities for engineering the media with the specified properties. The latest advancements in this field have prompted a surge of research in the new phenomenology, which could extend a range of functional capabilities and enable the development of innovative devices in the millimeter, terahertz (THz), and optical ranges.

Frequency conversion in dielectrics with nonlinearities of the second and third order has been investigated in optics, particularly, in the context of the second (SHG) and third (THG) harmonic generation. The recent studies have indicated that nonlinear photonic crystals (PhCs) and metamaterials (MMs) have significant potential for enhancement of the nonlinear activity associated with the mechanisms of field confinement, dispersion management and resonant intensification of the interacting waves. For example, it has been demonstrated in [1–5] that the PhCs dispersion can be tailored to facilitate the phase synchronism (The phase synchronism between pump wave and its harmonic is a prerequisite for efficient frequency conversion.) between the second harmonic and the pump wave of fundamental

frequency. The harmonic generation efficiency can be further increased when the pump wave frequencies are close to the PhC band edges [6–12] where the higher density of states provides favourable phase-matching conditions. The SHG efficiency also grows with the PhC thickness or the number of stacked layers [5].

Combinatorial frequency generation by mixing pump waves of two different frequencies provides alternative means for frequency conversion. The efficiency of mixing process can be dramatically increased in the layered structures, for example, at the higher order Wolf-Bragg resonances of the combinatorial frequencies generated in the anisotropic nonlinear dielectric slabs. As shown in [13], at the specific thickness of the layers illuminated by the plane waves of two tones, the mixing products reach their extremes and exhibit either giant growth of the peak intensity or full suppression. The global maxima and nulls at Wolf-Bragg resonances in the layer are achieved only at the particular combinations of the two frequencies $\omega_{1,2}$ of pump waves and the layer parameters and anisotropy.

The aim of this paper is to explore the mechanisms of the combinatorial frequency generation in the PhC composed of a periodic stack of binary anisotropic nonlinear dielectric

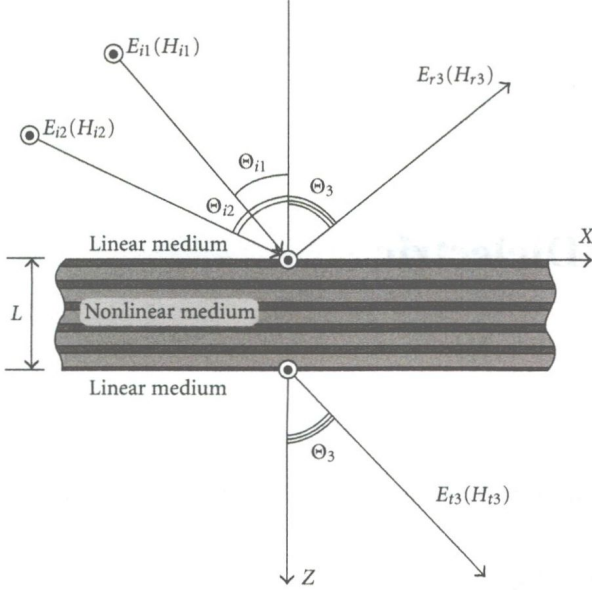


FIGURE 1: Geometry of the problem.

layers illuminated by two-tone pump waves that allows us to combine the effects of the resonance mixing with the dispersion control provided by the structure periodicity. Here the properties of the combinatorial frequencies generated by the nonlinear anisotropic dielectric PhC illuminated by plane waves of two tones are investigated. A generic approach, based on the transfer matrix method (TMM) [14], has been devised here to take into account nonlinear polarization of the constituent anisotropic layers and analyse frequency mixing of the two-tone plane waves obliquely incident on the PhC. The problem statement and the solution of the respective boundary value problem obtained in the three-wave approximation [15] are outlined in Section 2. The results of the numerical analysis and the properties of TM waves of combinatorial frequencies scattered by the nonlinear PhC are discussed in Section 3 and the main features of the three-wave mixing products generated by the anisotropic nonlinear PhCs are summarised in Conclusions.

2. Nonlinear Scattering in Three-Wave Mixing Process

Wave propagation and scattering in linear stratified media are usually modelled by TMM, which sequentially relates the fields at the layer interfaces, see, for example, [14, 16]. The TMM approach has also been applied to the study of optical harmonic generation and frequency mixing in 1D nonlinear-layered structures at normal incidence of the pump waves [17–20]. The nondepleted pump wave approximation has been usually employed taking into account multiple reflections from the layer interfaces and interference between all propagating waves, including the forward and backward propagating waves. A relatively simple approach based upon the TMM generalisation to a multiwavelength case has been proposed in [19] where interaction between the different

frequencies was described by the “effective” refractive index characteristic for each optical wave. The latter technique allows simulations of multiple optical wave interactions in the homogenised metamaterials as well as in PhCs.

In order to examine the three-wave mixing process in the 1D *anisotropic* PhC, it is necessary to generalise the TMM-based analysis for the case of two pump waves, incident at arbitrary angles. To elucidate the main features of the developed approach, we consider here a canonical PhC structure with the cross-section shown in Figure 1. It is composed of the periodic binary dielectric layers of thicknesses d_1 and d_2 and infinite extent in the x and y directions. The total thickness of the periodic stack is $L = N \cdot (d_1 + d_2)$, where N is the number of periods (unit cells). The PhC is surrounded by the linear homogeneous medium with the dielectric permittivity ϵ_a at $z \leq 0$ and $z \geq L$. It is illuminated by two plane waves of frequencies ω_1 and ω_2 incident at angles Θ_{i1} and Θ_{i2} , respectively, as shown in Figure 1.

Each layer has 6 mm class of anisotropy and is described by the linear dielectric permittivity tensor $\hat{\epsilon} = (\epsilon_{xx}, \epsilon_{xx}, \epsilon_{zz})$ and the second-order nonlinear susceptibility tensor $\hat{\chi}$:

$$\hat{\chi} = \begin{pmatrix} 0 & 0 & 0 & 0 & \chi_{xxz} & 0 \\ 0 & 0 & 0 & \chi_{xxz} & 0 & 0 \\ \chi_{xxx} & \chi_{xxx} & \chi_{zzz} & 0 & 0 & 0 \end{pmatrix}. \quad (1)$$

Owing to the structure uniformity in the xOy plane and symmetry of the tensors $\hat{\epsilon}$ and $\hat{\chi}$, we can assume without loss of generality that $\partial/\partial y = 0$. In this case, Maxwell's equations for TE and TM polarised waves are separated and can be treated independently. Only TM waves are considered in the rest of the paper (the analysis of TE waves is similar and somewhat simpler being unaffected by anisotropy of $\hat{\chi}$ defined in (1)). The electric $E_{x,z}$ and magnetic H_y field components of TM waves in each layer satisfy the following system of nonlinear equations:

$$\begin{aligned} \frac{\partial E_{xj}}{\partial z} - \frac{\partial E_{zj}}{\partial x} + \frac{1}{c} \frac{\partial H_{yj}}{\partial t} &= 0, \\ \frac{\partial H_{yj}}{\partial z} + \frac{\epsilon_{xxj}}{c} \frac{\partial E_{xj}}{\partial t} &= -\frac{4\pi}{c} \chi_{xxzj} \frac{\partial}{\partial t} (E_{xj} E_{zj}), \\ \frac{\partial H_{yj}}{\partial x} - \frac{\epsilon_{zzj}}{c} \frac{\partial E_{zj}}{\partial t} &= \frac{4\pi}{c} \left[\chi_{xxxj} \frac{\partial}{\partial t} (E_{xj} E_{xj}) + \chi_{zzzj} \frac{\partial}{\partial t} (E_{zj} E_{zj}) \right], \end{aligned} \quad (2)$$

where $j = 1, 2$ denotes the respective constituent nonlinear layer in the binary unit cell, c is the speed of light.

In the approximation of weak nonlinearity, the scattering characteristics of the TM waves can be obtained separately at each frequency by the harmonic balance method. Thus at the combinatorial frequency $\omega_3 = \omega_1 + \omega_2$, the system of nonlinear equations (2) can be reduced to inhomogeneous

Helmholtz equation for H_{yj} in each nonlinear anisotropic dielectric layer

$$\begin{aligned} & \frac{\partial^2 H_{yj}(\omega_3)}{\epsilon_{xxj} \partial z^2} + \left(k_3^2 - \frac{k_{x3}^2}{\epsilon_{zzj}} \right) H_{yj}(\omega_3) \\ &= 4\pi k_3 \left[2 \frac{\partial}{\partial x} \left(\frac{\chi_{xxxj}}{\epsilon_{zzj}} E_{xj}(\omega_1) E_{xj}(\omega_2) + \frac{\chi_{zzzj}}{\epsilon_{zzj}} E_{zj}(\omega_1) E_{zj}(\omega_2) \right) \right. \\ & \quad \left. - \frac{\chi_{xxzj}}{\epsilon_{xxj}} \frac{\partial}{\partial z} (E_{xj}(\omega_1) E_{zj}(\omega_2) + E_{xj}(\omega_2) E_{zj}(\omega_1)) \right], \end{aligned} \quad (3)$$

where $k_p = \omega_p/c$, $p = 1, 2, 3$ and $k_{x3} = k_3 \sqrt{\epsilon_a} \sin \Theta_3$. Since k_{x3} must obey the requirement of the waveform invariance along the layer interfaces, the phase synchronism condition in the three-wave mixing process [15] is enforced here in the following form:

$$k_{x3} = k_{x1} + k_{x2}, \quad (4)$$

where $k_{x1,2} = k_{1,2} \sqrt{\epsilon_a} \sin \Theta_{1,2}$. In order to make the solution procedure more transparent, we assume here that both incident pump waves of frequencies $\omega_{1,2}$ have the same amplitudes equal to unity. Generalisation to the case of unequal pump wave amplitudes is straightforward but the resulting expressions are more cumbersome.

The full solution of inhomogeneous equation (3) is composed of the partial and general solutions which can be represented in the form

$$\begin{aligned} H_{yj}^{(n)}(\omega_3, x, z) &= \left(A_j^{n+} e^{ik_{zLj}^{(3)} z} + A_j^{n-} e^{-ik_{zLj}^{(3)} z} + D_{1j}^{n+} e^{ik_{zLj}^{(3)} z} \right. \\ & \quad \left. + D_{2j}^{n+} e^{-ik_{zLj}^{(3)} z} + D_{1j}^{n-} e^{ik_{zLj}^{(3)} z} + D_{2j}^{n-} e^{-ik_{zLj}^{(3)} z} \right) \\ & \quad \times e^{-i\omega_3 t + ik_{x3} x}. \end{aligned} \quad (5)$$

Here the amplitude coefficients $A_j^{n\pm}$ are associated with the general solution of (3) and are determined by means of enforcing the continuity conditions for the tangential field components at the layer interfaces. The coefficients $D_{1j,2j}^{n\pm}$ represent the partial solution of inhomogeneous equation (3) and are expressed in terms of the refracted field

amplitudes in each layer at the pump wave frequencies ω_1 and ω_2 :

$$\begin{aligned} D_{1j}^{n+} &= \alpha_j \beta_j \frac{B_j^{n+}(\omega_1) B_j^{n+}(\omega_2)}{(k_{zLj}^+)^2 - (k_{zLj}^{(3)})^2}, \\ D_{2j}^{n+} &= \alpha_j \beta_j \frac{B_j^{n-}(\omega_1) B_j^{n-}(\omega_2)}{(k_{zLj}^+)^2 - (k_{zLj}^{(3)})^2}, \\ D_{1j}^{n-} &= \alpha_j \gamma_j \frac{B_j^{n+}(\omega_1) B_j^{n-}(\omega_2)}{(k_{zLj}^-)^2 - (k_{zLj}^{(3)})^2}, \\ D_{2j}^{n-} &= \alpha_j \gamma_j \frac{B_j^{n-}(\omega_1) B_j^{n+}(\omega_2)}{(k_{zLj}^-)^2 - (k_{zLj}^{(3)})^2}, \\ \alpha_j &= \frac{4\pi}{\epsilon_{zzj}} \frac{k_3}{k_1 k_2}, \\ \beta_j &= -k_{zLj}^+ k_{x1} k_{zLj}^{(2)} \frac{\chi_{xxzj}}{\epsilon_{xxj}} \\ & \quad - k_{x3} \left(\frac{\chi_{xxxj}}{\epsilon_{xxj}} k_{zLj}^{(1)} k_{zLj}^{(2)} + \frac{\chi_{zzzj} \epsilon_{xxj}}{\epsilon_{zzj}^2} k_{x1} k_{x2} \right) \\ \gamma_j &= k_{zLj}^- k_{x1} k_{zLj}^{(2)} \frac{\chi_{xxzj}}{\epsilon_{xxj}} \\ & \quad + k_{x3} \left(\frac{\chi_{xxxj}}{\epsilon_{xxj}} k_{zLj}^{(1)} k_{zLj}^{(2)} - \frac{\chi_{zzzj} \epsilon_{xxj}}{\epsilon_{zzj}^2} k_{x1} k_{x2} \right), \\ k_{zLj}^{\pm} &= k_{zLj}^{(1)} \pm k_{zLj}^{(2)}, \quad k_{zLj}^{(p)} = \sqrt{\left(k_p^2 - \frac{k_{xp}^2}{\epsilon_{zzj}} \right) \epsilon_{xxj}}, \\ & \quad p = 1, 2, 3; \quad j = 1, 2. \end{aligned} \quad (6)$$

Here $k_{zLj}^{(p)}$ are the z components of the wave vectors in j th layer at frequencies ω_p , respectively; superscript n identifies the period number in the stack. The coefficients $B_j^{n\pm}(\omega_{1,2})$ are the field amplitudes inside the j th layer of the n th period at the incident wave frequencies ω_1 and ω_2 . These coefficients are obtained by imposing the continuity conditions for the tangential field components of each pump wave of frequencies $\omega = \omega_{1,2}$ independently at the layer interfaces and can be represented in the form:

$$\begin{aligned} & B_j^{n\pm}(\omega_p) \\ &= \left(s_{11j}^{(n)}(\omega_p) \pm \frac{k_p}{k_{zLj}^{(p)}} \epsilon_{xxj} s_{21j}^{(n)}(\omega_p) \right) (1 + R(\omega_p)) + \frac{k_{za}^{(p)}}{k_p \epsilon_a} \left(s_{12j}^{(n)}(\omega_p) \pm \frac{k_p}{k_{zLj}^{(p)}} \epsilon_{xxj} s_{22j}^{(n)}(\omega_p) \right) (1 - R(\omega_p)), \\ & R(\omega_p) \\ &= \frac{M_{11}(\omega_p) + (k_{za}^{(p)} / (\epsilon_a k_p)) M_{12}(\omega_p) - (\epsilon_a k_p / k_{za}^{(p)}) M_{21}(\omega_p) - M_{22}(\omega_p)}{M_{11}(\omega_p) + (k_{za}^{(p)} / (\epsilon_a k_p)) M_{12}(\omega_p) + (\epsilon_a k_p / k_{za}^{(p)}) M_{21}(\omega_p) + M_{22}(\omega_p)}, \quad p = 1, 2, \end{aligned} \quad (7)$$

where $k_{za}^{(p)} = k_p \sqrt{\epsilon_a} \cos \Theta_{ip}$ is the longitudinal wavenumber in the surrounding medium and $R(\omega_p)$ is the reflection coefficient at frequency ω_p . The transfer matrix $\widehat{M}(\omega_p)$ of the finite linear periodic structure containing N periods can be expressed in terms of the transfer matrix $\widehat{m}(\omega_p) = \widehat{m}_{L1}(\omega_p) \widehat{m}_{L2}(\omega_p)$ of a single period using Abeles theorem [21]: $\widehat{M}(\omega_p) = (\widehat{m}(\omega_p))^N$, where $\widehat{m}_{L1,L2}(\omega_p)$ are the transfer matrices of the constituent layers of the unit cell. The matrices $\widehat{s}_j^{(n)}$ in (7) are defined as follows: $\widehat{s}_1^{(n)}(\omega_p) = (\widehat{m}(\omega_p)^{n-1})^{-1}$ and $\widehat{s}_2^{(n)}(\omega_p) = (\widehat{m}(\omega_p)^{n-1} \cdot \widehat{m}_{L1}(\omega_p))^{-1}$.

To satisfy the boundary conditions at the interfaces of the nonlinear layers at the combinatorial frequency ω_3 , the TMM procedure has to be modified in order to take into account the contribution of the frequency mixing products generated in each layer and subsequently refracted through the periodic stack. Namely, the fields at interfaces of the first layer in the binary unit cell are related as follows:

$$\begin{pmatrix} H_{y1}^{(1)}(\omega_3, x, 0) \\ E_{x1}^{(1)}(\omega_3, x, 0) \end{pmatrix} = \widehat{m}_{L1}(\omega_3) \begin{pmatrix} H_{y1}^{(1)}(\omega_3, x, d_1) \\ E_{x1}^{(1)}(\omega_3, x, d_1) \end{pmatrix} + \widehat{m}_{L1}(\omega_3) \begin{pmatrix} \tau_{11}(d_1) \\ \xi_{11}(d_1) \end{pmatrix}. \quad (8)$$

Similarly, for the second layer we obtain

$$\begin{pmatrix} H_{y1}^{(1)}(\omega_3, x, d_1) \\ E_{x1}^{(1)}(\omega_3, x, d_1) \end{pmatrix} = \widehat{m}_{L2}(\omega_3) \begin{pmatrix} H_{y2}^{(1)}(\omega_3, x, d_1 + d_2) \\ E_{x2}^{(1)}(\omega_3, x, d_1 + d_2) \end{pmatrix} + \widehat{m}_{L2}(\omega_3) \begin{pmatrix} \tau_{21}(d_1 + d_2) \\ \xi_{21}(d_1 + d_2) \end{pmatrix}. \quad (9)$$

Thus, (8) and (9) define the interrelation between the fields at the external interfaces of the constituent unit cell. After applying the boundary conditions sequentially to all N unit cells, the fields at the stack outer interfaces can be represented in the form:

$$\begin{aligned} & \begin{pmatrix} H_{y1}^{(1)}(\omega_3, x, 0) \\ E_{x1}^{(1)}(\omega_3, x, 0) \end{pmatrix} \\ &= \widehat{M}(\omega_3) \begin{pmatrix} H_{y2}^{(N)}(\omega_3, x, L) \\ E_{x2}^{(N)}(\omega_3, x, L) \end{pmatrix} + \widehat{m}_{L1}(\omega_3) \begin{pmatrix} \tau_{11}(d_1) \\ \xi_{11}(d_1) \end{pmatrix} \\ &+ \widehat{m}_{L1}(\omega_3) \widehat{m}_{L2}(\omega_3) \begin{pmatrix} \tau_{21}(d_1 + d_2) \\ \xi_{21}(d_1 + d_2) \end{pmatrix} \\ &+ \dots + \widehat{M}(\omega_3) \begin{pmatrix} \tau_{2N}(L) \\ \xi_{2N}(L) \end{pmatrix}. \end{aligned} \quad (10)$$

Here τ_{jn} and ξ_{jn} contain the terms proportional to coefficients $D_{1j,2j}^{n\pm}$, $j = 1, 2$:

$$\begin{aligned} \tau_{jn} &= D_{1j}^{n+} \sigma_{1j}^+ + D_{2j}^{n+} \sigma_{1j}^- + D_{1j}^{n-} \sigma_{2j}^+ + D_{2j}^{n-} \sigma_{2j}^-, \\ \xi_{jn} &= D_{1j}^{n+} \sigma_{3j}^+ + D_{2j}^{n+} \sigma_{3j}^- + D_{1j}^{n-} \sigma_{4j}^+ + D_{2j}^{n-} \sigma_{4j}^-, \\ \sigma_{1j}^\pm &= \cos k_{zLj}^{(3)} d_j \pm i \frac{k_{zLj}^+}{k_{zLj}^{(3)}} \sin k_{zLj}^{(3)} d_j - e^{\pm i k_{zLj}^+ d_j}, \\ \sigma_{2j}^\pm &= \cos k_{zLj}^{(3)} d_j \pm i \frac{k_{zLj}^-}{k_{zLj}^{(3)}} \sin k_{zLj}^{(3)} d_j - e^{\pm i k_{zLj}^- d_j}, \\ \sigma_{3j}^\pm &= \frac{c}{\omega_3 \epsilon_{xxj}} \left(i \sin k_{zLj}^{(3)} d_j \pm \frac{k_{zLj}^+}{k_{zLj}^{(3)}} \cos k_{zLj}^{(3)} d_j \mp \frac{k_{zLj}^+}{k_{zLj}^{(3)}} e^{\pm i k_{zLj}^+ d_j} \right), \\ \sigma_{4j}^\pm &= \frac{c}{\omega_3 \epsilon_{xxj}} \left(i \sin k_{zLj}^{(3)} d_j \pm \frac{k_{zLj}^-}{k_{zLj}^{(3)}} \cos k_{zLj}^{(3)} d_j \mp \frac{k_{zLj}^-}{k_{zLj}^{(3)}} e^{\pm i k_{zLj}^- d_j} \right). \end{aligned} \quad (11)$$

The magnetic field of frequency ω_3 emitted from the stack of nonlinear layers into the surrounding homogeneous medium has the form:

$$H_y^a(\omega_3) = e^{-i\omega_3 t + i k_{x3} x} \begin{cases} F_r e^{-i k_{za}^{(3)} z}, & z \leq 0, \\ F_t e^{i k_{za}^{(3)} z}, & z \geq L, \end{cases} \quad (12)$$

where $k_{za}^{(3)} = \sqrt{k_3^2 \epsilon_a - k_{x3}^2}$ is the longitudinal wave number of the wave at frequency ω_3 in the homogeneous media and the nonlinear scattering coefficient F_r and F_t are determined by enforcing the interface boundary conditions at $z = 0, L$.

Finally, by combining (5), (10), and (12) we obtain the sought coefficients $F_{r,t}$:

$$\begin{aligned} F_r &= \left(\frac{k_3 \epsilon_a}{k_{za}^{(3)}} (\widehat{\eta}_N)_{21} + (\widehat{\eta}_N)_{22} \right) \lambda_1 - \left(\frac{k_3 \epsilon_a}{k_{za}^{(3)}} (\widehat{\eta}_N)_{11} + (\widehat{\eta}_N)_{12} \right) \lambda_2, \\ F_t &= - \left(\lambda_1 + \lambda_2 \frac{k_3 \epsilon_a}{k_{za}^{(3)}} \right), \end{aligned} \quad (13)$$

where

$$\lambda_p = \frac{1}{\Delta} \sum_{n=1}^N \left[(\widehat{\eta}'_n)_{p1} \tau_{1n} + (\widehat{\eta}'_n)_{p2} \xi_{1n} + (\widehat{\eta}_n)_{p1} \tau_{2n} + (\widehat{\eta}_n)_{p2} \xi_{2n} \right], \quad p = 1, 2;$$

$$\begin{aligned} \Delta &= (\widehat{\eta}_N)_{11} + (\widehat{\eta}_N)_{22} + \frac{k_{za}^{(3)}}{k_3 \epsilon_a} (\widehat{\eta}_N)_{12} + \frac{k_3 \epsilon_a}{k_{za}^{(3)}} (\widehat{\eta}_N)_{21}; \\ \widehat{\eta}_n &= [\widehat{m}(\omega_3)]^n, \quad \widehat{\eta}'_n = \widehat{\eta}_{n-1} \widehat{m}_{L1}(\omega_3), \quad \widehat{\eta}_N = \widehat{M}(\omega_3). \end{aligned} \quad (14)$$

It is necessary to note that $F_{r,t}$ in (13) always remain finite inspite of the fact that coefficients $D_{1j,2j}^{n\pm}$ have singularity at $k_{zLj}^\pm = k_{zLj}^{(3)}$. However, it can be shown that coefficients

$A_j^{\eta\pm}$ in (5) contain exactly the same pole as $D_{1j,2j}^{\eta\pm}$ at $\Theta_{i1} = \Theta_{i2}$, and their combined contribution is finite at all frequencies and incidence angles.

Thus the modified TMM approach presented in this section gives the closed-form expressions for the nonlinear scattering coefficients of the finite PhC composed of the binary nonlinear layers. The obtained analytical formulations not only provide a qualitative insight in the formation of the nonlinear response and the properties of the scattered fields but also enable fast quantitative analysis of the specific PhC configurations.

The results of numerical simulations based upon the analytical solutions obtained here are presented in the next section to illustrate the effects of structure and materials parameters on the properties TM waves of combinatorial frequencies generated by nonlinear PhC in the three-wave mixing process.

3. Properties and Mechanisms of Nonlinear Scattering by Finite Periodic Stacks

The analytical solutions for the coefficients $F_{r,t}$ obtained in the preceding section have allowed us to examine the mechanisms of nonlinear scattering in 1D anisotropic nonlinear PhCs. The effects of the constituent layer parameters, unit cell aspect ratio, and the pump wave frequencies $\omega_{1,2}$ and incidence angles $\Theta_{i1,2}$ on the properties of the waves of combinatorial frequency $\omega_3 = \omega_1 + \omega_2$ generated in the three-wave mixing process have been analysed with the aim of increasing the efficiency of nonlinear processes in the artificial medium.

To illustrate the features of the frequency mixing in the 1D nonlinear anisotropic PhCs, the characteristics of the combinatorial frequency waves are discussed here with the examples of periodic stacks of binary anisotropic dielectric layers of CdS and ZnO described by the tensors $\hat{\epsilon}$ and $\hat{\chi}$ (1) with the following parameters [22]:

$$\text{CdS: } \epsilon_{xx1} = 5.382, \epsilon_{zz1} = 5.457 (\alpha_1 = \epsilon_{xx1}/\epsilon_{zz1} = 0.986), \chi_{xxz1} = 2.1 \times 10^{-7}, \chi_{zxx1} = 1.92 \times 10^{-7}, \chi_{zzz1} = 3.78 \times 10^{-7};$$

$$\text{ZnO: } \epsilon_{xx2} = 1.4, \epsilon_{zz2} = 2.6 (\alpha_2 = \epsilon_{xx2}/\epsilon_{zz2} = 0.538), \chi_{xxz2} = 2.82 \times 10^{-8}, \chi_{zxx2} = 2.58 \times 10^{-8}, \chi_{zzz2} = 8.58 \times 10^{-8}.$$

The constituent layer thicknesses are $d_1 = 0.08$ mm and $d_2 = 0.05$ mm, unless specifically defined. Exterior of the layer stack in Figure 1 is an air with permittivity $\epsilon_a = 1$.

3.1. Spectral Efficiency of the Combinatorial Frequency Generation. PhCs are known to be instrumental in enhancing the SHG and THG efficiency by choosing the pump wave frequency close to the PhC band edge. Therefore, it was interesting to explore whether similar facility could be exploited for the combinatorial frequencies generated in the three-wave mixing process. The spectral bands of a periodic stack of binary linear anisotropic dielectric layers have been inferred first from the reflectance $|R(\omega)|$ of the pump waves. Figure 2 illustrates $|R(\omega)|$ for the TM wave incident at angle

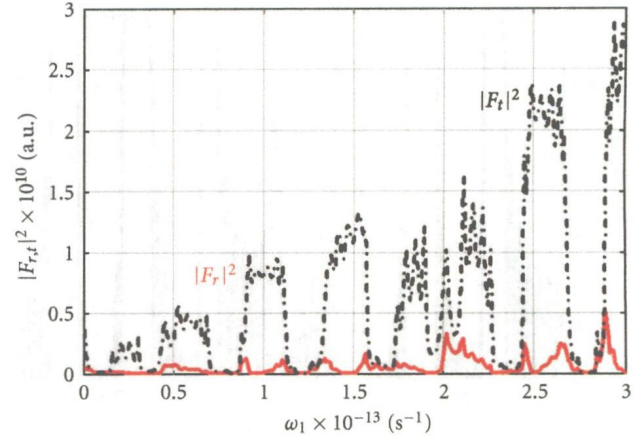


FIGURE 2: Reflectance of plane TM wave incident at $\Theta_i = 30^\circ$ on the periodic stack of $N = 7$ binary dielectric layers of thicknesses $d_1 = 0.08$ mm and $d_2 = 0.05$ mm.

$\Theta_{i1} = 30^\circ$ on the periodic stack containing $N = 7$ unit cells. The bandgaps, corresponding to $|R(\omega)| \approx 1$, are clearly observable in Figure 2, but it is necessary to note that the respective frequency bands change with the incidence angle and layers' parameters.

The field intensities $|F_{r,t}|^2$ at the combinatorial frequency $\omega_3 = \omega_1 + \omega_2$ generated in the same structure are shown in Figure 3 for variable frequency ω_1 of a pump wave incident at $\Theta_{i1} = 30^\circ$, while the frequency $\omega_2 = 1.135 \times 10^{13} \text{ s}^{-1}$ of the other pump wave, incident at $\Theta_{i2} = 45^\circ$, was fixed at the passband edge. Comparison of Figures 2 and 3 demonstrates strong correlation between $|F_{r,t}|^2$ and $|R(\omega)|$. However, in contrast to SHG and THG, the band edges have little effect on the ω_3 generation efficiency, namely, $|F_t|^2$ reaches its maxima inside the transparency bands, and only $|F_r|^2$ exhibits small kinks at the band edges when frequency ω_1 of the first pump wave varies.

Figure 3 also shows that the peak intensity $|F_t|^2$ grows with ω_1 and the efficiency of the frequency conversion is higher when the ω_1 remains inside the pump wave transparency bands. This effect can be attributed to the increase of the pump wave interaction length at the higher frequencies further assisted by the enhanced mixing efficiency at Wolf-Bragg resonances of Bloch waves in the finite PhCs. It is noteworthy that $(N-1)$ resonances occur in each transparency band of the N -cell stack. At these resonances $|R(\omega)| = 0$ as the stack overall thickness equals an integer number of Bloch half-waves with the wavenumbers $\bar{k}(\omega)$, that is, $N\bar{k}(\omega)(d_1 + d_2) = \pi q$, $q = 0, \pm 1, \pm 2, \dots$, where $\bar{k}(\omega)$ is defined by the relation $\cos \bar{k}(d_1 + d_2) = (m_{11} + m_{22})/2$, m_{11} and m_{22} are elements of the unit cell transfer matrix $\hat{m}(\omega)$ defined in connection with (7).

3.2. Effect of the Stack Thickness. As indicated in the preceding section, the number N of stacked unit cells and thickness of the whole stack may have strong impact on the efficiency of harmonic generation in nonlinear PhC. This effect has been predicted by the analytical formulations (13) and

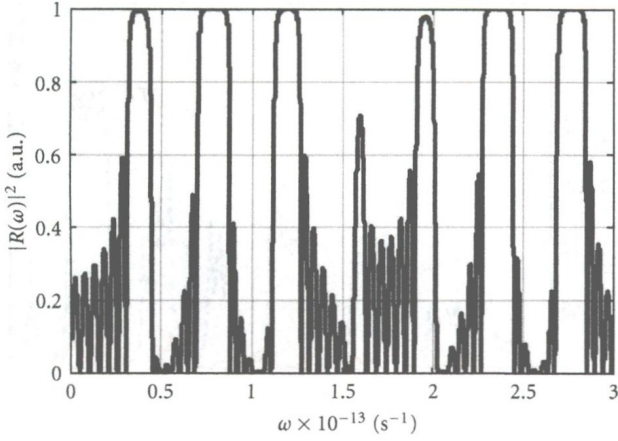


FIGURE 3: The field intensity at frequency $\omega_3 = \omega_1 + \omega_2$ radiated in the reverse ($|F_r|^2$: red solid line) and forward ($|F_t|^2$: black dash-dot line) directions of the z -axis at $\Theta_{i1} = 30^\circ$; $\Theta_{i2} = 45^\circ$, $N = 7$, $d_1 = 0.08$ mm, $d_2 = 0.05$ mm, and $\omega_2 = 1.135 \times 10^{13}$ s $^{-1}$.

confirmed by the numerical simulations in Figure 4. Indeed, the field intensity $|F_{r,t}|^2$ exhibits nonmonotonic dependences on the number N of unit cells in the stack as illustrated by Figure 4 for two different combinatorial frequencies $\omega_3 = \omega_1 + \omega_2$ (the pump wave frequencies ω_1 and ω_2 are close to the PhC band edges in both cases). Indeed, Figure 4(a) shows that $|F_r|^2$ has maxima at $N = 32, 57, 89, \dots$, whereas $|F_t|^2$ has a higher peak at $N = 32$ and then follows almost the same pattern as $|F_r|^2$. However, at the higher frequency ω_1 , maxima of $|F_{r,t}|^2$ occur at $N = 108$ and $N = 127$ as shown in Figure 4(b), where the peak values of $|F_t|^2$ are about two orders of magnitude higher than those in Figure 4(a) and about 20 times larger than for $|F_r|^2$. The $|F_{r,t}|^2$ can also exhibit giant growth and reach their extrema at Wolf-Bragg resonances of very high orders in rather thick stacks with the special combinations of the pump wave frequencies, incidence angles, and the layer parameters as suggested in [13].

3.3. Effect of the Pump Wave Incidence Angles on the Frequency Mixing Efficiency. Harmonic generation in 1D PhCs are usually analysed at normal incidence of pump wave on the stacked layers. In the case of combinatorial frequency generation by a pair of pump waves, incident at different angles, an additional degree of freedom exists in realising the phase synchronism and controlling the whole frequency mixing process. To gain insight in the effect of the incidence angle on the combinatorial frequency field intensities, $|F_{r,t}|^2$ have been simulated at variable incidence angle Θ_{i1} and fixed angle Θ_{i2} of the respective pump waves and different number of the unit cells in the stack: $N = 7, 15, 25$.

Examination of $|F_{r,t}(\Theta_{i1})|^2$ in Figure 5 shows that when the stack is relatively thin ($N = 7$), both $|F_r|^2$ and $|F_t|^2$ exhibit similar behaviour and smoothly vary with Θ_{i1} . However, additional resonances arise in the thicker stacks, and the $|F_{r,t}(\Theta_{i1})|^2$ dependencies qualitatively change. Several factors are responsible for these alterations. At first,

dissimilar reflectance and transmittance of the individual pump waves have significant effect on the ratio of the pump wave amplitudes in the three-wave mixing process. Secondly, angular variations of the PhC transparency bands become more noticeable in the thicker stacks. Finally, the higher order spatial harmonics, which can resonate in thicker stacks, contribute to the combinatorial frequency generation.

Both the reflectance/transmittance of pump waves and the phase synchronism in the mixing process are essentially dependent on the permittivities and anisotropy of the constituent binary layers. Therefore the effect of the constituent layer parameters has been assessed first to discriminate contributions of the aforementioned mechanisms to the combinatorial frequency generation. In order to evaluate the effect of the layer anisotropy, the intensities $|F_t(\Theta_{i1})|^2$ have been simulated at the modified permittivity ratios $\epsilon_{xx1}/\epsilon_{zz1} = 2\alpha_1$, $\epsilon_{xx2}/\epsilon_{zz2} = 2\alpha_2$, and $\epsilon_{xx1}/\epsilon_{zz1} = \alpha_1/2$, $\epsilon_{xx2}/\epsilon_{zz2} = \alpha_2/2$ and are shown in Figure 6. Comparison of the plots in Figure 5(b) for $\epsilon_{xx1}/\epsilon_{zz1} = \alpha_1$, $\epsilon_{xx2}/\epsilon_{zz2} = \alpha_2$ with the respective plots in Figure 6 for the modified tensor $\hat{\epsilon}$ demonstrates that variations of the layer anisotropy qualitatively alter the efficiency of the combinatorial frequency generation. Namely, we can observe that when the layer anisotropy deviates from the specified values of $\alpha_{1,2}$ in either direction, the combinatorial frequency intensity considerably decreases, from a few times to several orders of magnitude. Furthermore, additional angular undulations of the field intensity occur at several incidence angles, Figure 6, being inflicted by the resonances of the higher order spatial harmonics.

3.4. Effects of Constituent Layer Thicknesses and Resonance Enhancement of Frequency Conversion. The stack overall thickness may have profound influence on the frequency mixing efficiency. This can be the result of the increased number of unit cells in the stack as illustrated in Figure 4 or variations in the thicknesses of the constituent layers. The earlier studies have demonstrated that the efficiency of combinatorial frequency generation can significantly vary with thickness of an individual nonlinear layer at the higher order Wolf-Bragg resonances [13]. This suggests that the aspect ratio of the binary layers in the unit cell as well as the unit cell size can provide independent controls of the dispersion and the pump wave reflectance/transmittance. In order to elucidate this effect, the intensities $|F_{r,t}|^2$ at frequency $\omega_3 = \omega_1 + \omega_2$ have been analysed at the variable thickness of one layer, while thickness of the other was fixed. Figure 7 displays $|F_{r,t}|^2$ for a stack with $N = 7$ unit cells illuminated by the pump waves incident at $\Theta_{i1} = 38^\circ$ and $\Theta_{i2} = 45^\circ$ corresponding to the maximal intensity of $|F_{r,t}|^2$ for the reference unit cell with $d_1 = 0.08$ mm and $d_2 = 0.05$ mm in Figure 5. It can be seen that both $|F_{r,t}|^2$ grow with thickness of the layers in the period, while $|F_t|^2$ always remains greater than $|F_r|^2$. It is necessary to note that the growth rate of the $|F_{r,t}|^2$ versus d_1 (Figure 7(b)) is higher than that versus d_2 (Figure 7(a)) for nearly an order of magnitude. This effect is directly related to the fact that the components of the nonlinear susceptibility tensor $\hat{\chi}$ in